

7828999 0007739 TT2 RHM

Ultra-Low Noise (Hetero Structured In GaAs FET)

Type	Application	Absolute maximum ratings (Ta=25°C)				Electrical characteristics (Ta=25°C)				
		V _{DS} (V)	I _D	P _D (mW)	T _{ch} (°C)	PG Typ. (dB)	NF Typ. (dB)	f (GHz)	I _{DSS} (mA)	Y _{fs} (ms)
RHF1205CM	DBS RF	3	70	160	125	10.5	0.70	12.0	10~70	30m and over
RHF1204CM	DBS RF	3	70	160	125	10.5	0.80	12.0	10~70	30m and over
RHF1252CM	DBS RF	4	85	200	125	10	1.1	12.0	12~80	30m and over
RHF1251CM	DBS RF	4	85	200	125	10	1.2	12.0	12~80	30m and over

